NSN 5961-01-165-0590

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-165-0590

Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.195 inches

Internal Configuration:

Junction contact-double emitter

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-18

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, emitter-to-base, collector open and 50.0 breakdown voltage, emitter to collector, base open and 50.0

breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

10.00 nanoamperes zero-gate-voltage source current preset

Transfer Ratio:

1.5 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0